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FDMS86101

N-Channel PowerTrench® MOSFET

100 V, 60 A, 8 mΩ

Features

- Max $r_{DS(on)} = 8 \text{ m}\Omega$ at $V_{GS} = 10 \text{ V}$, $I_D = 13 \text{ A}$
- Max $r_{DS(on)} = 13.5 \text{ m}\Omega$ at $V_{GS} = 6 \text{ V}$, $I_D = 9.5 \text{ A}$
- Advanced Package and Silicon combination for low $r_{DS(on)}$ and high efficiency
- MSL1 robust package design
- 100% UIL tested
- 100% R_g tested
- RoHS Compliant

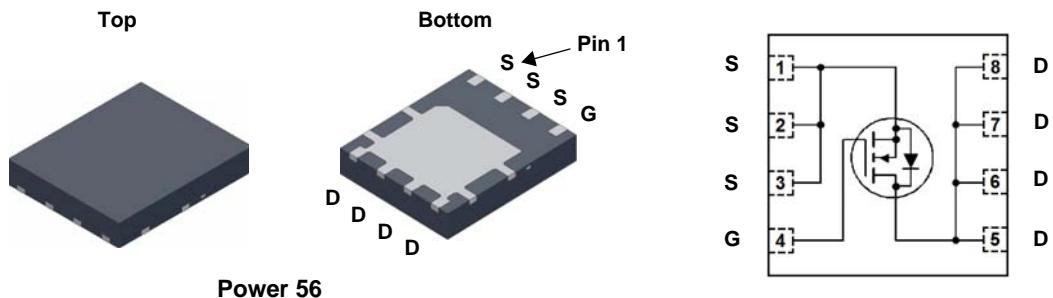


General Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced Power Trench® process that has been especially tailored to minimize the on-state resistance and yet maintain superior switching performance.

Application

■ DC-DC Conversion



MOSFET Maximum Ratings $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Ratings	Units	
V_{DS}	Drain to Source Voltage	100	V	
V_{GS}	Gate to Source Voltage	± 20	V	
I_D	Drain Current -Continuous	$T_C = 25^\circ\text{C}$	A	
	-Continuous	$T_A = 25^\circ\text{C}$		
	-Pulsed			
E_{AS}	Single Pulse Avalanche Energy	(Note 3)	173	mJ
P_D	Power Dissipation	$T_C = 25^\circ\text{C}$	W	
	Power Dissipation	$T_A = 25^\circ\text{C}$		
$T_{J, T_{STG}}$	Operating and Storage Junction Temperature Range	-55 to +150	°C	

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case	1.2	$^{\circ}\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMS86101	FDMS86101	Power 56	13 "	12 mm	3000 units

Electrical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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Off Characteristics

BV_{DSS}	Drain to Source Breakdown Voltage	$I_D = 250 \mu\text{A}, V_{GS} = 0 \text{ V}$	100			V
$\frac{\Delta \text{BV}_{\text{DSS}}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \mu\text{A}$, referenced to 25°C		66		$\text{mV}/^\circ\text{C}$
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 80 \text{ V}, V_{GS} = 0 \text{ V}$			800	nA
I_{GSS}	Gate to Source Leakage Current, Forward	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			100	nA

On Characteristics

$V_{GS(\text{th})}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu\text{A}$	2.0	2.9	4.0	V
$\frac{\Delta V_{GS(\text{th})}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \mu\text{A}$, referenced to 25°C		-9		$\text{mV}/^\circ\text{C}$
$r_{DS(\text{on})}$	Static Drain to Source On Resistance	$V_{GS} = 10 \text{ V}, I_D = 13 \text{ A}$		6.3	8	$\text{m}\Omega$
		$V_{GS} = 6 \text{ V}, I_D = 9.5 \text{ A}$		8.4	13.5	
		$V_{GS} = 10 \text{ V}, I_D = 13 \text{ A}, T_J = 125^\circ\text{C}$		10.9	14	
g_{FS}	Forward Transconductance	$V_{DS} = 10 \text{ V}, I_D = 13 \text{ A}$		45		s

Dynamic Characteristics

C_{iss}	Input Capacitance	$V_{DS} = 50 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		2255	3000	pF
C_{oss}	Output Capacitance			460	610	pF
C_{rss}	Reverse Transfer Capacitance			30	45	pF
R_g	Gate Resistance		0.1	1.0	3.0	Ω

Switching Characteristics

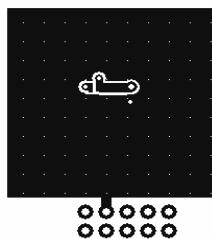
$t_{\text{d(on)}}$	Turn-On Delay Time	$V_{DD} = 50 \text{ V}, I_D = 13 \text{ A}, V_{GS} = 10 \text{ V}, R_{\text{GEN}} = 6 \Omega$		15	27	ns
t_r	Rise Time			11	20	ns
$t_{\text{d(off)}}$	Turn-Off Delay Time			27	44	ns
t_f	Fall Time			7	13	ns
Q_g	Total Gate Charge	$V_{GS} = 0 \text{ V to } 10 \text{ V}$		39	55	nC
	Total Gate Charge		$V_{DD} = 50 \text{ V}, I_D = 13 \text{ A}$	22	31	nC
Q_{gs}	Gate to Source Charge			9.5		nC
Q_{gd}	Gate to Drain "Miller" Charge			10.8		nC

Drain-Source Diode Characteristics

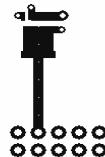
V_{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_S = 2.1 \text{ A}$ (Note 2)		0.7	1.2	V
		$V_{GS} = 0 \text{ V}, I_S = 13 \text{ A}$ (Note 2)		0.8	1.3	
t_{rr}	Reverse Recovery Time	$I_F = 13 \text{ A}, di/dt = 100 \text{ A}/\mu\text{s}$		56	90	ns
				61	98	nC

Notes:

1. $R_{\theta JA}$ is determined with the device mounted on a 1 in^2 pad 2 oz copper pad on a $1.5 \times 1.5 \text{ in.}$ board of FR-4 material. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.



a. $50^\circ\text{C}/\text{W}$ when mounted on a 1 in^2 pad of 2 oz copper.



b. $125^\circ\text{C}/\text{W}$ when mounted on a minimum pad of 2 oz copper.

2. Pulse Test: Pulse Width $< 300 \mu\text{s}$, Duty cycle $< 2.0\%$.

3. E_{AS} of 173 mJ is based on starting $T_J = 25^\circ\text{C}$, $L = 0.3 \text{ mH}$, $I_{AS} = 34 \text{ A}$, $V_{DD} = 75 \text{ V}$, $V_{GS} = 10 \text{ V}$. 100% test at $L = 0.1 \text{ mH}$, $I_{AS} = 49 \text{ A}$.

Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

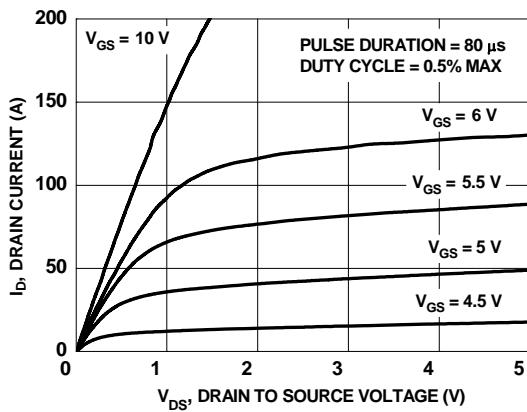


Figure 1. On Region Characteristics

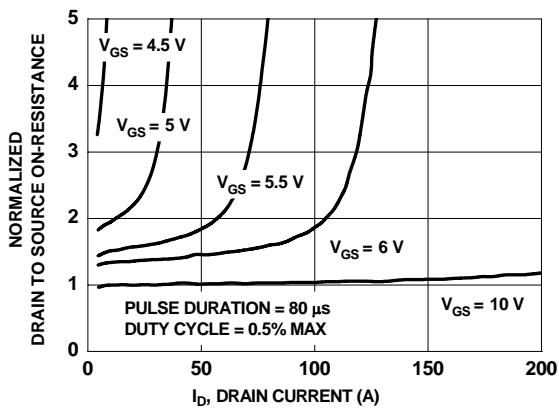


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

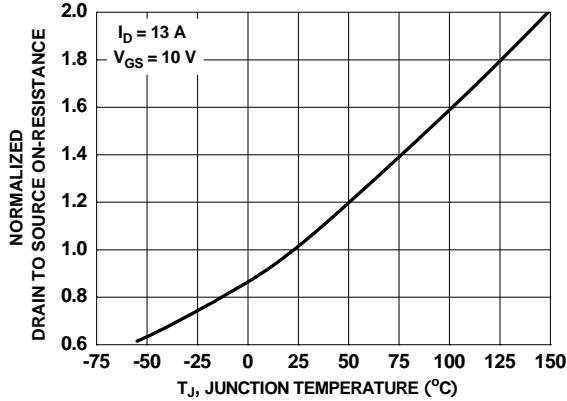


Figure 3. Normalized On Resistance vs Junction Temperature

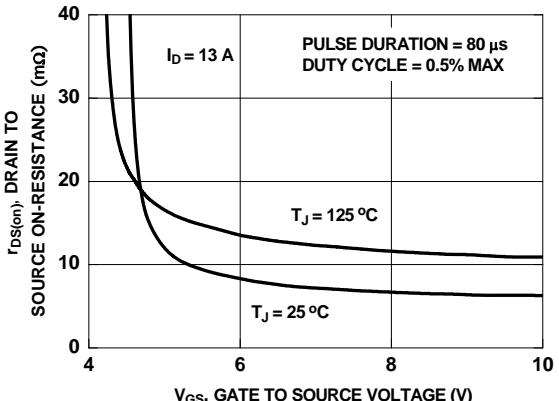


Figure 4. On-Resistance vs Gate to Source Voltage

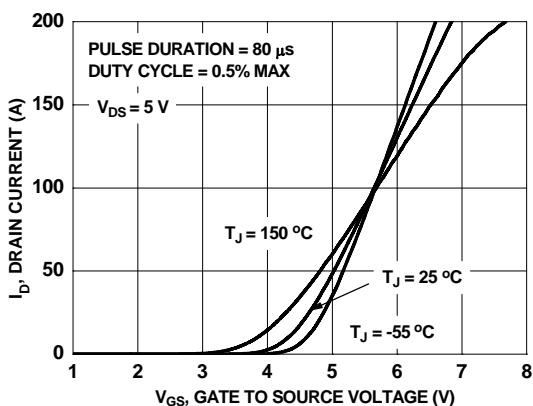


Figure 5. Transfer Characteristics

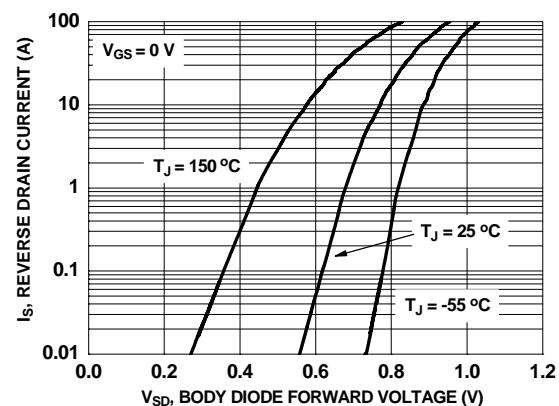


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

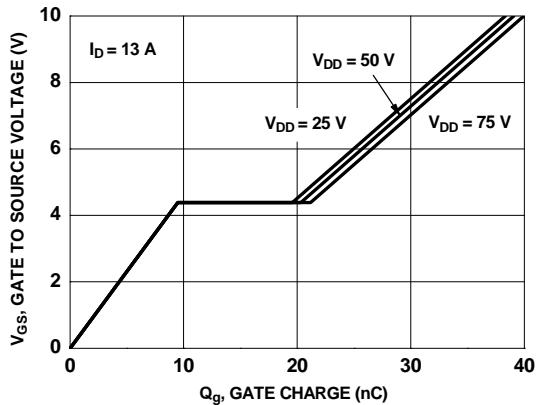


Figure 7. Gate Charge Characteristics

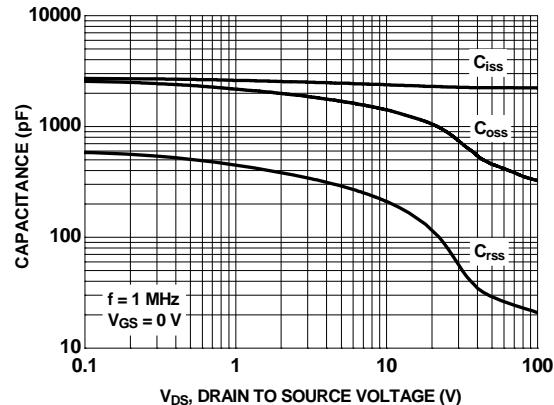


Figure 8. Capacitance vs Drain to Source Voltage

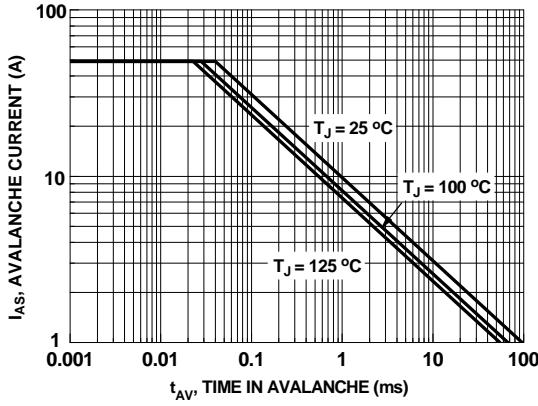


Figure 9. Unclamped Inductive Switching Capability

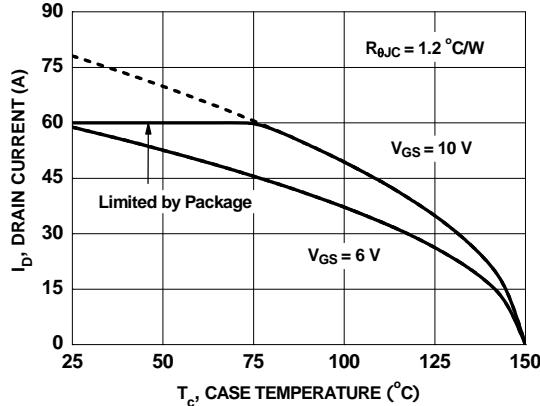


Figure 10. Maximum Continuous Drain Current vs Case Temperature

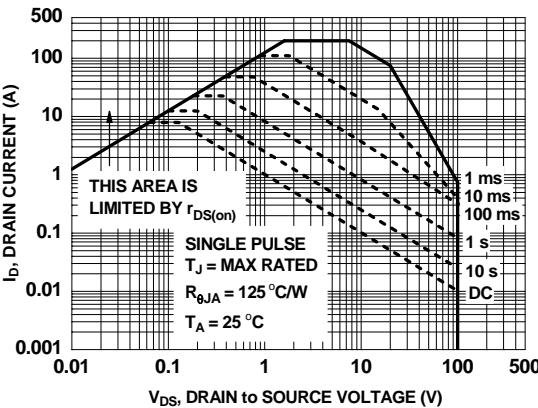


Figure 11. Forward Bias Safe Operating Area

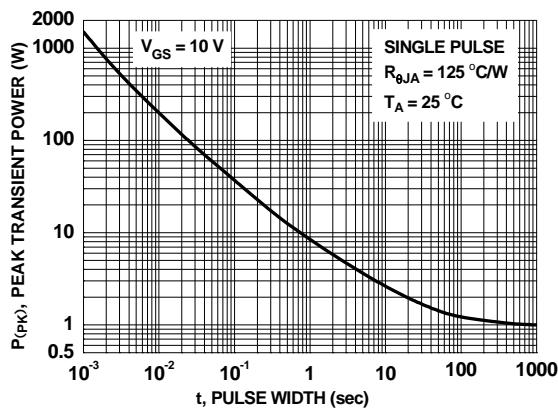


Figure 12. Single Pulse Maximum Power Dissipation

Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

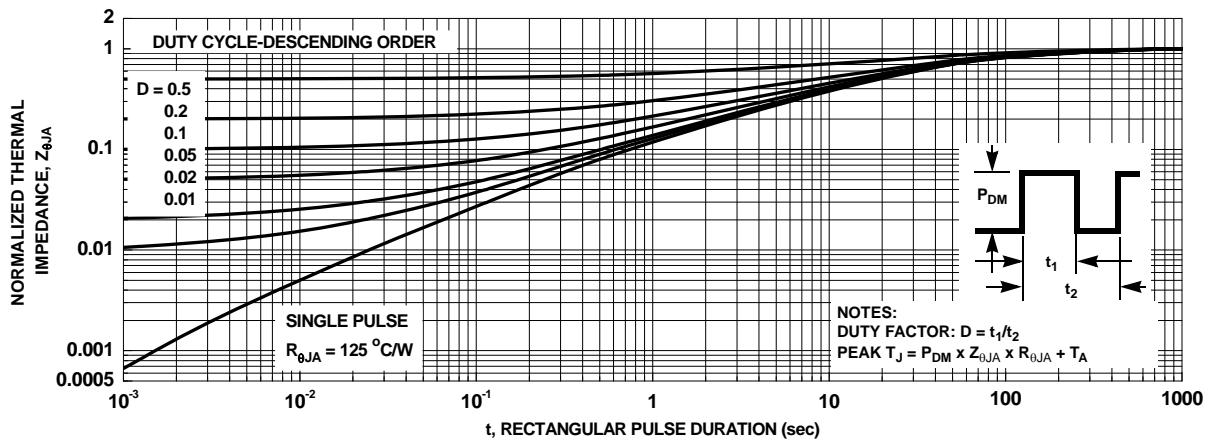
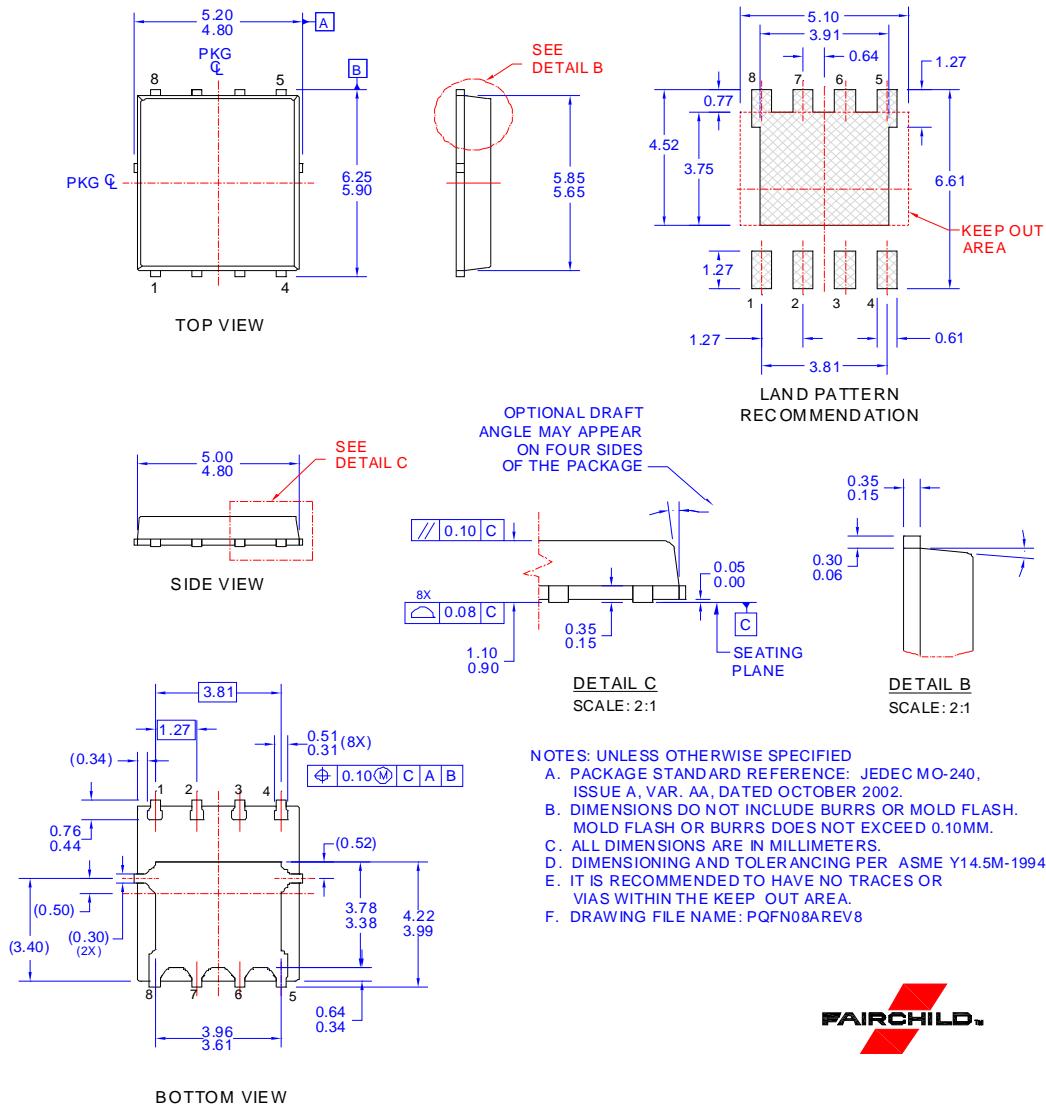


Figure 13. Junction-to-Ambient Transient Thermal Response Curve

Dimensional Outline and Pad Layout



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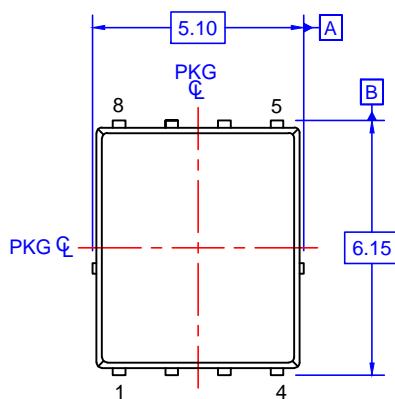
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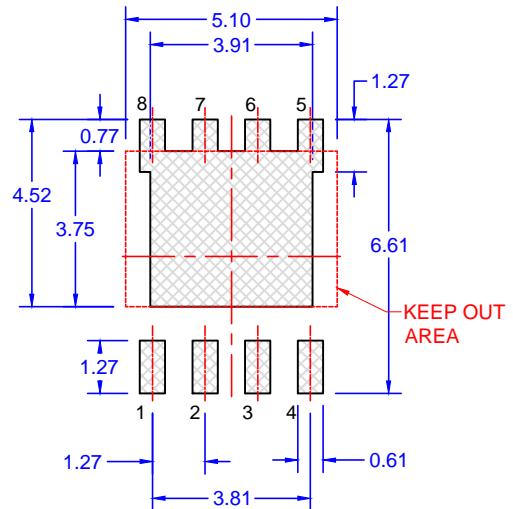
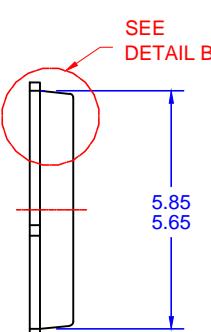
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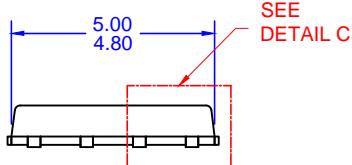
Rev. I77



TOP VIEW

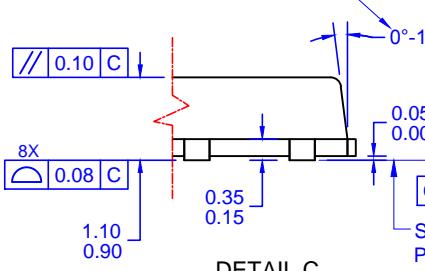


LAND PATTERN RECOMMENDATION

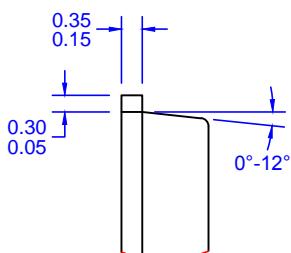


SIDE VIEW

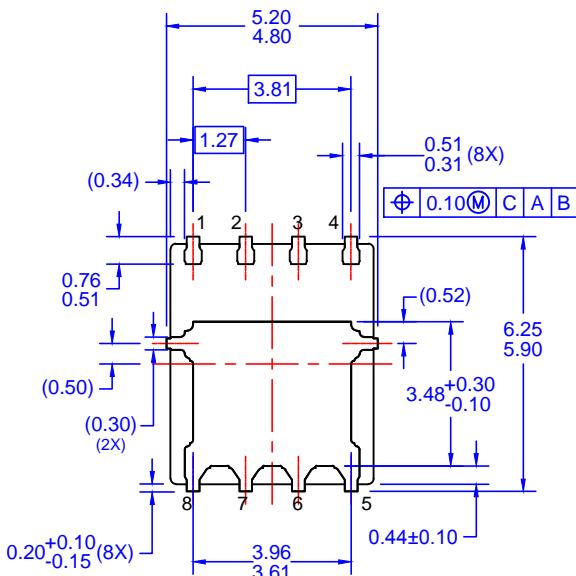
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DETAIL C



DETAIL B



BOTTOM VIEW

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- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибутором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «JONHON», а так же официальным дистрибутором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «FORSTAR».



JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели, кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



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